
2SK1528(L), 2SK1528(S)

Silicon N-Channel MOS FET

HITACHI

November 1996

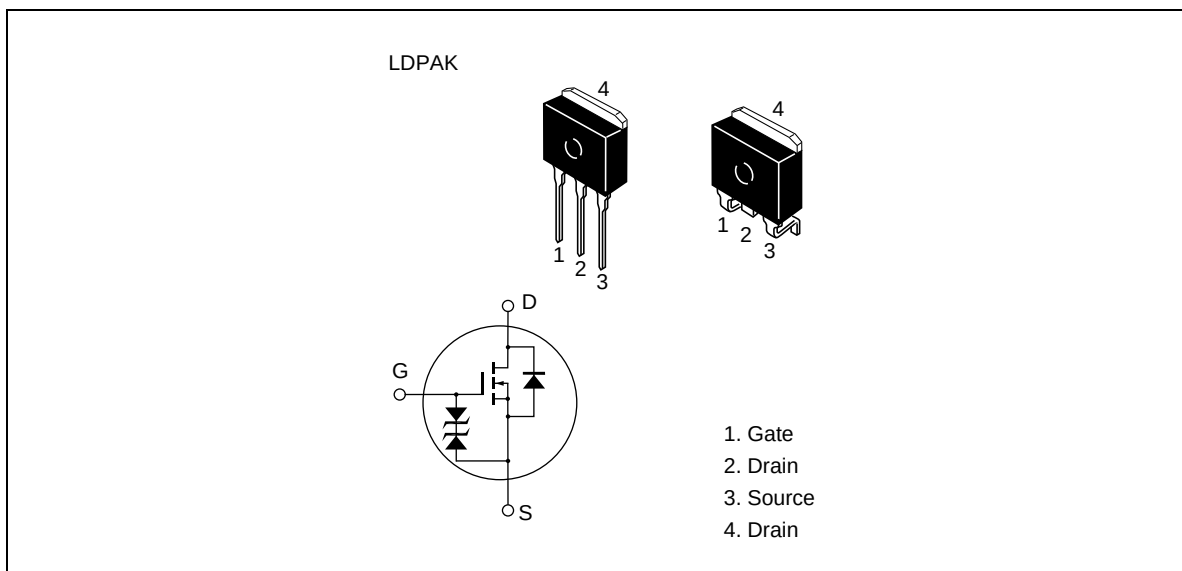
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

Outline



2SK1528(L), 2SK1528(S)

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	900	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I_D	4	A
Drain peak current	$I_{D(pulse)}^{*1}$	10	A
Body to drain diode reverse drain current	I_{DR}	4	A
Channel dissipation	Pch^{*2}	60	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
2. Value at $T_c = 25^\circ C$

2SK1528(L), 2SK1528(S)

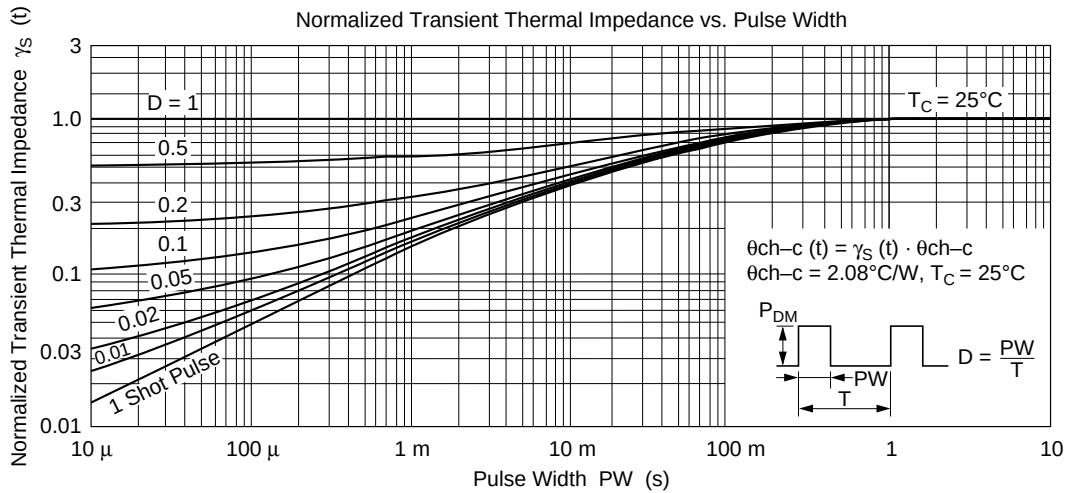
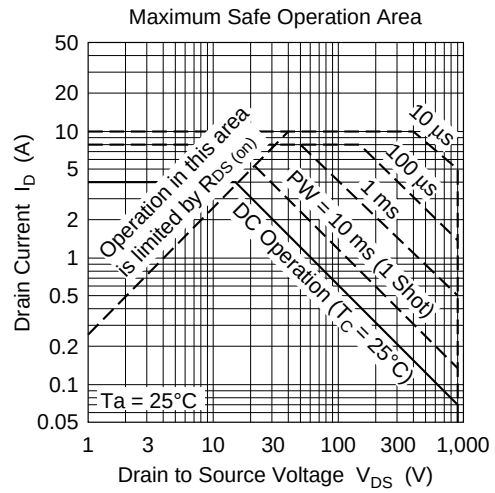
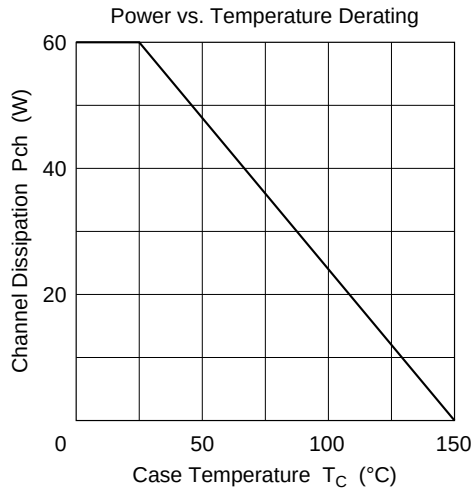
Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	900	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	250	μA	$V_{DS} = 720 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static Drain to source on state resistance	$R_{DS(on)}$	—	3.0	4.0	Ω	$I_D = 2 \text{ A}$, $V_{GS} = 10 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	1.7	2.7	—	S	$I_D = 2 \text{ A}$, $V_{DS} = 20 \text{ V}^{*1}$
Input capacitance	C_{iss}	—	740	—	pF	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	305	—	pF	
Reverse transfer capacitance	C_{rss}	—	150	—	pF	
Turn-on delay time	$t_{d(on)}$	—	15	—	ns	$I_D = 2 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_L = 15 \text{ }\Omega$
Rise time	t_r	—	60	—	ns	
Turn-off delay time	$t_{d(off)}$	—	100	—	ns	
Fall time	t_f	—	80	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.9	—	V	$I_F = 4 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	800	—	ns	$I_F = 4 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 100 \text{ A}/\mu\text{s}$

Note 1. Pulse test

See characteristic curves of 2SK1340.

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